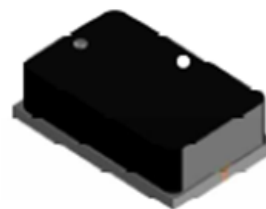


Features

- Wide Frequency Range:
50 MHz to 6 GHz in 3 Bands
- Surface Mount SP2T Switch in Compact Outline:
8 x 5 x 2.5 mm (L x W x H)
- Higher Average Power Handling than Plastic Packaged
- MMIC Switches: 100 W CW
- High RF Peak Power: 500 W
- Low Insertion Loss: 0.3 dB
- High IIP3: 65 dBm
- Operates From: 5 V & -180 V
- RoHS* Compliant



CS206

Applications

- High Power Transmit/Receive (TR) Switching
- Active Receiver Protection

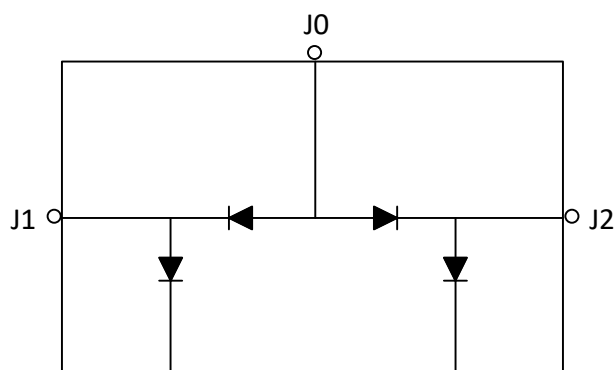
Description

The MSW206x-206 series of SP2T TR silicon PIN diode switches are manufactured using a proven hybrid manufacturing process incorporating high voltage PIN diodes and passive devices integrated within a ceramic substrate. This low profile, compact, surface mount component, offers superior low and high signal performance to comparable MMIC devices in QFN packages. The SP2T switches are designed in an asymmetrical series & series-shunt topology to optimize Tx & Rx performance. .

Using PIN diodes with lower thermal resistance ($<10^{\circ}\text{C/W}$), RF CW incident power levels of +50 dBm and RF peak incident power levels of +57 dBm are very achievable in higher power cold and hot switching applications @ +85°C. The lower PIN diode series resistance ($<1\ \Omega$), coupled with the longer minority carrier lifetime, ($>3\ \mu\text{s}$), provides better IIP3 distortion values $>+65\ \text{dBm}$.

These MSW206x-206 SP2T switches are designed to be used in higher power switch applications, operating from 20 MHz to 6000 MHz, requiring high volume, surface mount, solder re-flow manufacturing. These products are durable, reliable, and capable of meeting all military, commercial, and industrial environments.

Functional Schematic



Ordering Information

| Part # ¹ | Package |
|---------------------|-----------------------|
| MSW206x-206-T | tube |
| MSW206x-206-R | 250 or 500 piece reel |
| MSW206x-206-W | waffle pack |
| MSW206x-206-E | RF evaluation board |

1. x determines frequency, replace x with:
 0 = 20 - 1200 MHz
 1 = 200 - 4500 MHz
 2 = 1.5 - 6.5 GHz

MSW2060-206**Electrical Specifications: Freq. = 20 - 1200 MHz, $T_A = +25^\circ\text{C}$, $P_{IN} = 0\text{ dBm}$, $Z_0 = 50\ \Omega$**

| Parameter | Test Conditions | Units | Min. | Typ. | Max. |
|----------------------------------|---|---------------|------|------|------|
| Insertion Loss | Condition 1:port J0 to J1 Condition 2: port J0 to J2 | dB | — | 0.25 | 0.35 |
| Return Loss | Condition 1:port J0 to J1 Condition 2: port J0 to J2 | dB | 20 | 23 | — |
| Isolation | Condition 1:port J0 to J1 Condition 2: port J0 to J2 | dB | 49 | 53 | — |
| CW Incident Power ² | Source & Load VSWR = 1.5:1 | dBm | — | 50 | — |
| Peak Incident Power ² | Source & Load VSWR = 1.5:1, Pulse Width = 10 μs , Duty Cycle = 1% | dBm | — | 57 | — |
| Switching Time ³ | 10% - 90% RF Voltage, TTL rep rate = 100 | μs | — | 2 | 3 |
| Input IP3 | F1 = 500 MHz, F2 = 510 MHz, P1=P2=40 dBm Measured on path biased to low loss state | dBm | 60 | 65 | — |

MSW2061-206**Electrical Specifications: Freq. = 200 - 4500 MHz, $T_A = +25^\circ\text{C}$, $P_{IN} = 0\text{ dBm}$, $Z_0 = 50\ \Omega$**

| Parameter | Test Conditions | Units | Min. | Typ. | Max. |
|----------------------------------|---|---------------|------|------|------|
| Insertion Loss | Condition 1:port J0 to J1 Condition 2: port J0 to J2 | dB | — | 0.5 | 0.7 |
| Return Loss | Condition 1:port J0 to J1 Condition 2: port J0 to J2 | dB | 14 | 16 | — |
| Isolation | Condition 1:port J0 to J1 Condition 2: port J0 to J2 | dB | 32 | 35 | — |
| CW Incident Power ² | Source & Load VSWR = 1.5:1 | dBm | — | 50 | — |
| Peak Incident Power ² | Source & Load VSWR = 1.5:1, Pulse Width = 10 μs , Duty Cycle = 1% | dBm | — | 57 | — |
| Switching Time ³ | 10% - 90% RF Voltage, TTL rep rate = 100 | μs | — | 1 | 2 |
| Input IP3 | F1 = 2000 MHz, F2 = 2010 MHz, P1=P2=40 dBm Measured on path biased to low loss state | dBm | 60 | 65 | — |

MSW2062-206**Electrical Specifications: Freq. = 1.5 - 6.5 GHz, $T_A = +25^\circ\text{C}$, $P_{IN} = 0 \text{ dBm}$, $Z_0 = 50 \Omega$**

| Parameter | Test Conditions | Units | Min. | Typ. | Max. |
|----------------------------------|---|---------------|------|------|------|
| Insertion Loss | Condition 1: port J0 to J1 Condition 2: port J0 to J2 | dB | — | 0.7 | 0.9 |
| Return Loss | Condition 1: port J0 to J1 Condition 2: port J0 to J2 | dB | 11 | 13 | — |
| Isolation | Condition 1: port J0 to J1 Condition 2: port J0 to J2 | dB | 31 | 34 | — |
| CW Incident Power ² | Source & Load VSWR = 1.5:1 | dBm | — | 50 | — |
| Peak Incident Power ² | Source & Load VSWR = 1.5:1, Pulse Width = 10 μs , Duty Cycle = 1% | dBm | — | 57 | — |
| Switching Time ³ | 10% - 90% RF Voltage, TTL rep rate = 100 | μs | — | 1 | 2 |
| Input IP3 | F1 = 2000 MHz, F2 = 2010 MHz, P1=P2=40 dBm Measured on path biased to low loss state | dBm | 60 | 65 | — |

Bias State Conditions:

State 1 (J0 - J1 in low insertion loss state):
a. J1: -50 mA, 180 V (ON)

State 2 (J0 - J2 in low insertion loss state):
a. J2: +25 mA, 1 V (OFF)

- PIN diode DC reverse voltage to maintain high resistance in the OFF PIN diode is determined by RF frequency, incident power, and VSWR as well as by the characteristics of the diode. The minimum reverse bias voltage values are provided in this datasheet. The input signal level applied for small signal testing is approximately 0 dBm.
- Switching time (50% TTL - 10/90% RF Voltage) is a function of the PIN diode driver performance as well as the characteristics of the diode. An RC "current spiking network" is used on the driver output to provide a transient current to rapidly remove stored charge from the PIN diode. Typical component values are: R = 50 to 220 Ω and C = 470 to 1,000 pF. Monzite's MDD050N181Q16A or 99235 (<https://monzite.com/>) is the recommended PIN diode driver to interface with the MSW206x-206 series SP2T switches.

Truth Table

| Port J0 - J1 | Port J0 - J2 | Bias: J1 | Bias: J2 |
|-----------------|-----------------|----------------|----------------|
| Low Loss | Isolation | -180 V, -50 mA | +1 V, +25 mA |
| Isolation | Low Loss | +1 V, +25 mA | -180 V, -50 mA |

RF Bias Network Component Values

| Part # | Frequency (MHz) | Inductors | DC Blocking Capacitors | RF Bypass Capacitors |
|-------------|-----------------|-------------|------------------------|----------------------|
| MSW2060-206 | 50 - 1000 | 4.7 μ H | 0.1 μ F | 0.1 μ F |
| MSW2061-206 | 400 - 4000 | 82 nH | 27 pF | 270 pF |
| MSW2062-206 | 2000 - 6000 | 33 nH | 22 pF | 33 pF |

Minimum Reverse Bias Voltage: $P_{INC} = 100$ W CW, $Z_0 = 50 \Omega$ with 1.5:1 VSWR

| Part # | F = 20 MHz | F = 100 MHz | F = 200 MHz | F = 400 MHz | F = 1 GHz | F = 4 GHz |
|-------------|----------------------|----------------------|----------------------|----------------------|----------------------|----------------------|
| MSW2060-206 | -180 V | -150 V | -110 V | -75 V | -35 V | N/A |
| MSW2061-206 | N/A | N/A | -150 V | -110 V | -55 V | -25 V |
| MSW2062-206 | (F = 1 GHz) -55 V | (F = 2 GHz) -28 V | (F = 3 GHz) -28 V | (F = 4 GHz) -28 V | (F = 5 GHz) -28 V | (F = 6 GHz) -28 V |

The minimum reverse bias voltage required to maintain a PIN diode out of conduction in the presence of a large RF signal is given by:

$$|V_{DC}| = \frac{|V_{RF}|}{\sqrt{1 + \left[\left(\frac{0.0142 \times f_{MHz} \times W_{mils}^2}{V_{RF} \times \sqrt{D}} \right) \times \left(1 + \sqrt{1 + \left(\frac{0.056 \times V_{RF} \times \sqrt{D}}{W_{mils}} \right)^2} \right)^2 \right]}}$$

Where:

- $|V_{DC}|$ = magnitude of the minimum DC reverse bias voltage
- $|V_{RF}|$ = magnitude of the peak RF voltage (including the effects of the VSWR)
- f_{MHz} = lowest RF signal frequency expressed in MHz
- D = duty factor of the RF signal
- W_{MILS} = thickness of the diode I layer, expressed in mils (thousands of an inch)

R. Caverly and G. Hiller, -Establishing the Minimum Reverse Bias for a PIN Diode in a High Power Switch, IEEE Transactions on Microwave Theory and Techniques, Vol.38, No.12, December 1990

Absolute Maximum Ratings

| Parameter | Conditions | Absolute Maximum |
|---|--|------------------|
| Forward Current | J1 or J2 Port | 250 mA |
| Reverse Voltage | J1 or J2 Port | 300 V |
| Forward Diode Voltage | $I_F = 250$ mA | 1.2 V |
| CW Incident Power Handling ⁴ | Source & Load VSWR = 1.5:1, $T_C = 85^\circ\text{C}$, cold switching | 50 dBm |
| Peak Incident Power Handling ⁴ | RX or Ant Port Source & Load VSWR = 1.5:1, $T_C = 85^\circ\text{C}$, cold switching Pulse Width = 10 μs , Duty Cycle = 1% | 57 dBm |
| Total Dissipated RF & DC Power ⁵ | $T_C = 85^\circ\text{C}$, cold switching | 12 W |
| Junction Temperature | — | +175°C |
| Operating Temperature | — | -65°C to +125°C |
| Storage Temperature | — | -65°C to +150°C |
| Assembly Temperature | $t = 10$ s | +260°C |

4. For hot switching, PIN diode driver must transition from forward bias to reverse bias and reverse bias to forward bias within 100 ns with a parallel RC spiking network at the driver output.
5. Backside RF and DC grounding area of device must be completely solder attached to the RF circuit board vias for proper electrical and thermal circuit grounding.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

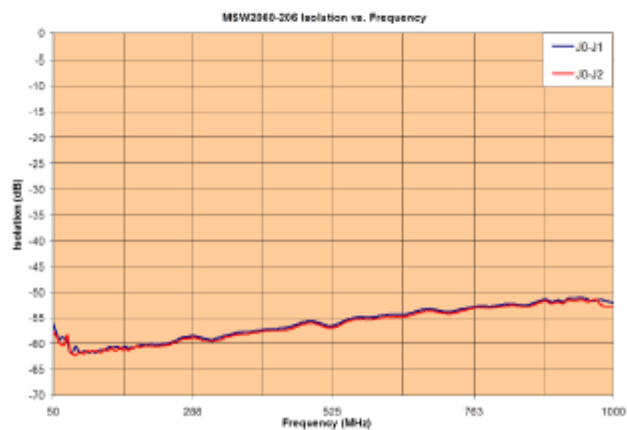
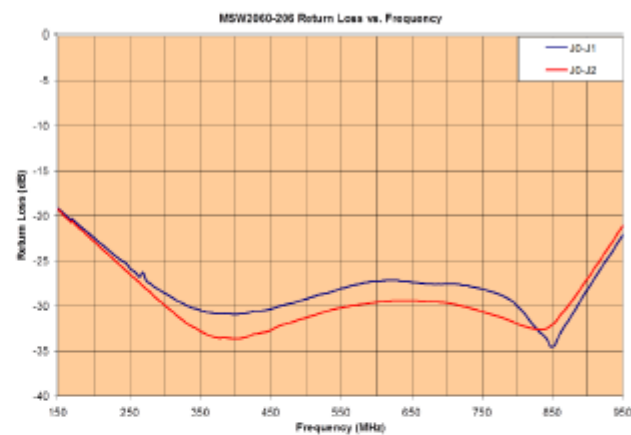
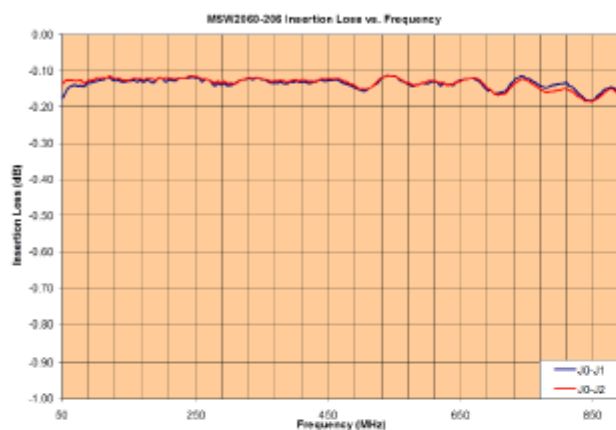
These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these Class 1C (HBM) devices. The moisture sensitivity level (MSL) rating for this part is MSL 2.

Environmental Capabilities

The MSW206x-206 series diodes are capable of meeting the environmental requirements of MIL-STD-202 and MIL-STD-750.

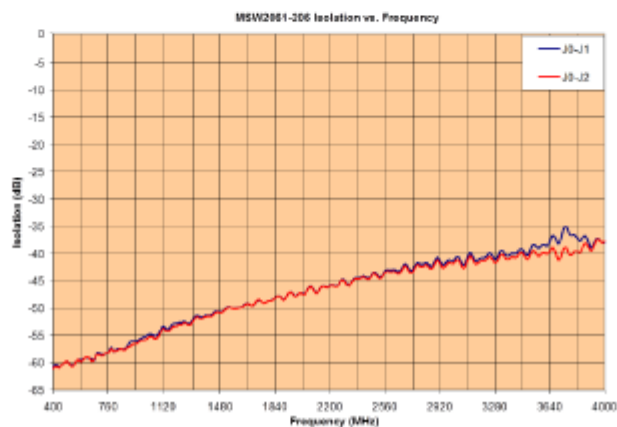
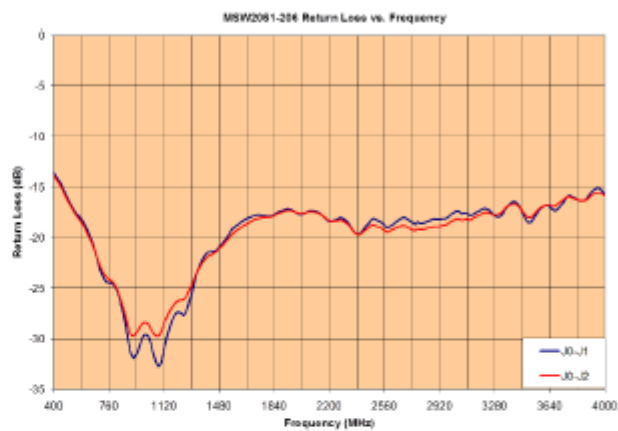
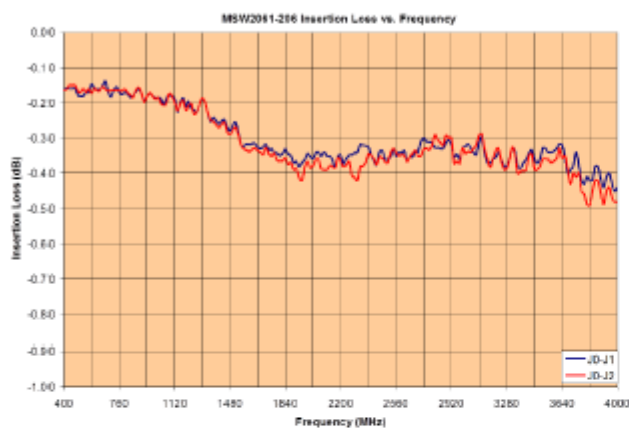
MSW2060-206 Small Signal Typical Performance

$Z_0 = 50 \Omega$, $T_A = +25^\circ\text{C}$ (Unless Otherwise Defined)



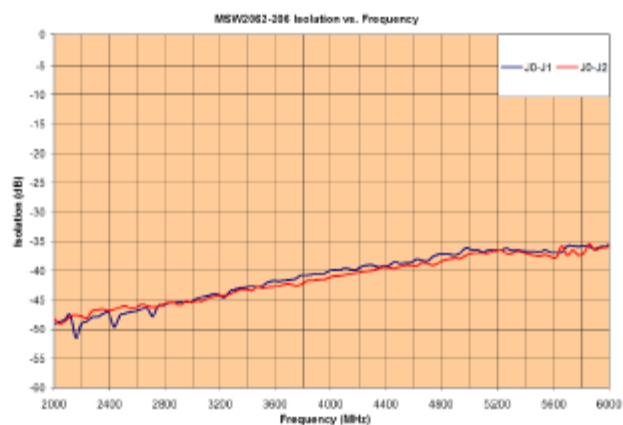
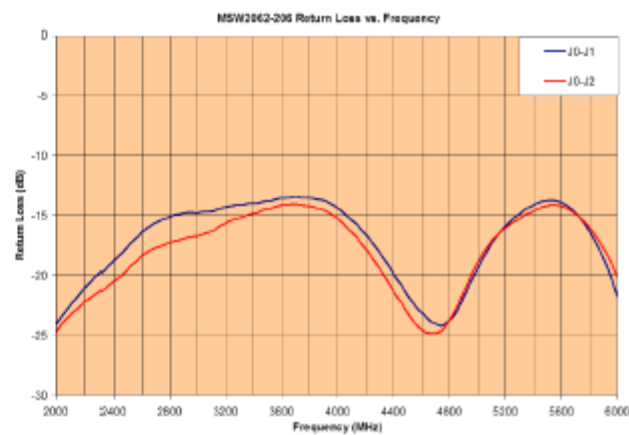
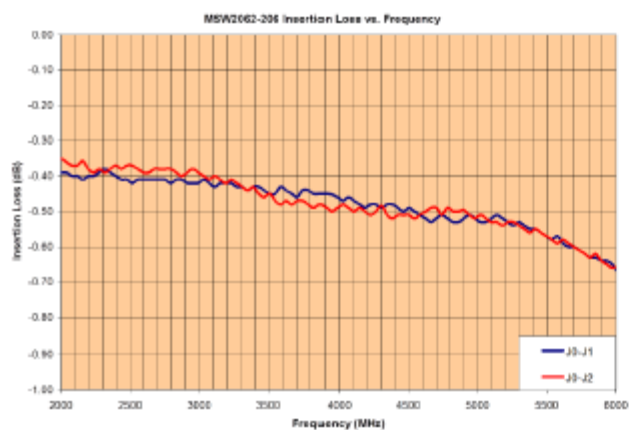
MSW2061-206 Small Signal Typical Performance

$Z_0 = 50 \Omega$, $T_A = +25^\circ\text{C}$ (Unless Otherwise Defined)

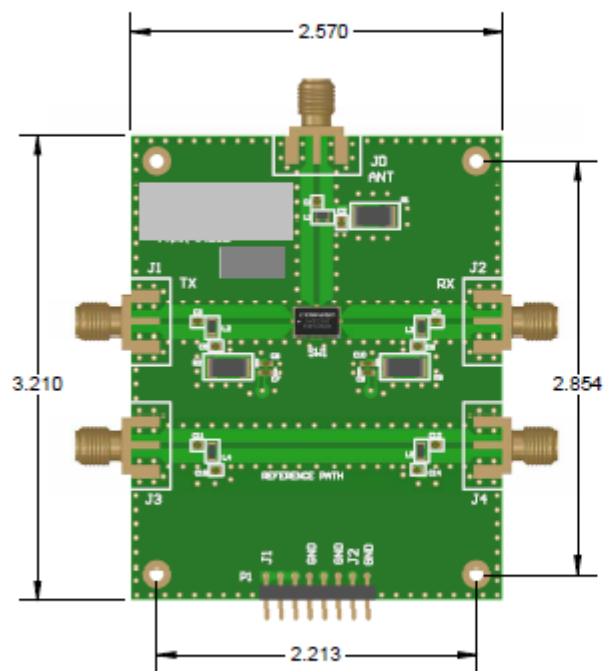


MSW2062-206 Small Signal Typical Performance

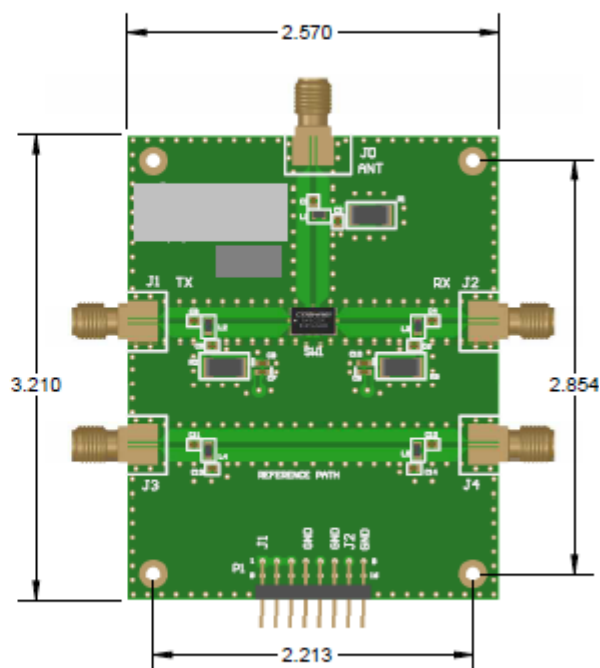
$Z_0 = 50 \Omega$, $T_A = +25^\circ\text{C}$ (Unless Otherwise Defined)



SP2T Switch Evaluation Board Layouts



APPLIES TO THE FOLLOWING EVAL BOARDS:
CS206 - BAND 1 / BAND 2



APPLIES TO THE FOLLOWING EVAL BOARDS:
CS206 - BAND 3

Evaluation Board Parts List

| MSW2060-206 Band 1 | | |
|------------------------------|--------------|------------|
| Part | Value | Case Style |
| C1, C3, C4, C11, C12 | 470 pF | 0603 |
| C2, C5, C6, C13, C14 | 470 pF | 0603 |
| ⁶ C7, C8, C9, C10 | 470 pF | 0603 |
| L1 - L7 | 600 Ω | 0603 |
| R1 | 130 Ω | 2512 |
| R2, R3 | 150 Ω | 2512 |

| MSW2061-206 Band 2 | | |
|------------------------------|--------------|------------|
| Part | Value | Case Style |
| C1, C3, C4, C11, C12 | 47 pF | 0603 |
| C2, C5, C6, C13, C14 | 220 pF | 0603 |
| ⁶ C7, C8, C9, C10 | 1000 pF | 0603 |
| L1 - L5 | 43 nH | 0603 |
| R1 | 130 Ω | 2512 |
| R2, R3 | 150 Ω | 2512 |

| MSW2062-206 Band 3 | | |
|------------------------------|--------------|------------|
| Part | Value | Case Style |
| C1, C3, C4, C11, C12 | 10 pF | 0603 |
| C2, C5, C6, C13, C14 | 33 pF | 0603 |
| ⁶ C7, C8, C9, C10 | 1000 pF | 0603 |
| L1 - L5 | 8.2 nH | 0603 |
| R1 | 130 Ω | 2512 |
| R2, R3 | 150 Ω | 2512 |

6. Second bypass capacitor is optional.

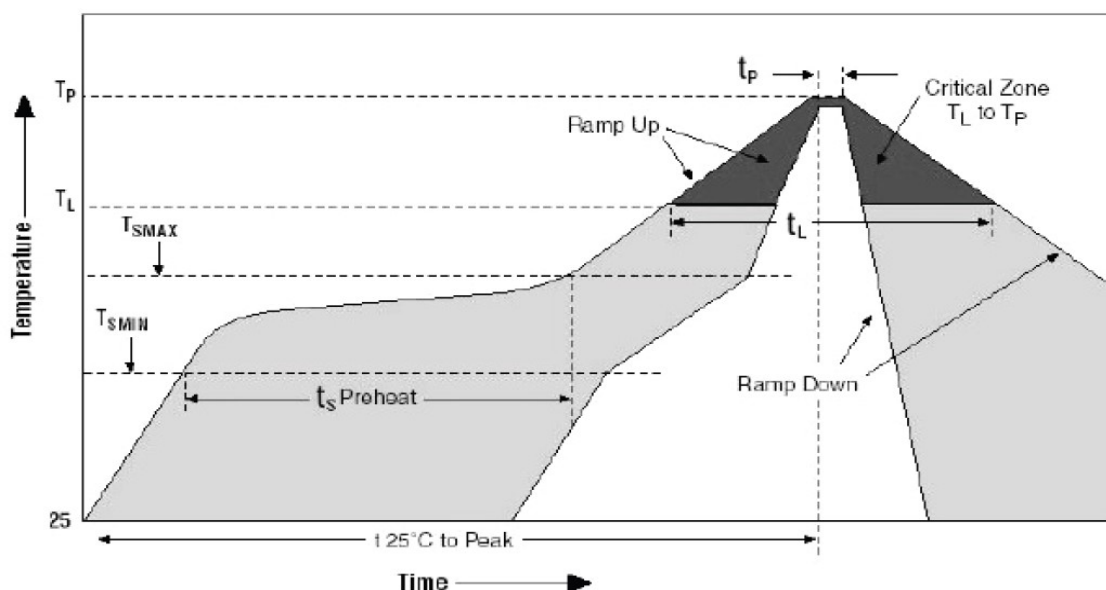
Assembly Instructions

SP2T PIN Diodes may be placed onto circuit boards with pick and place manufacturing equipment from tape and reel. The devices are attached to the circuit using conventional solder re-flow or wave soldering procedures with RoHS type or Sn 60 / Pb 40 type solders.

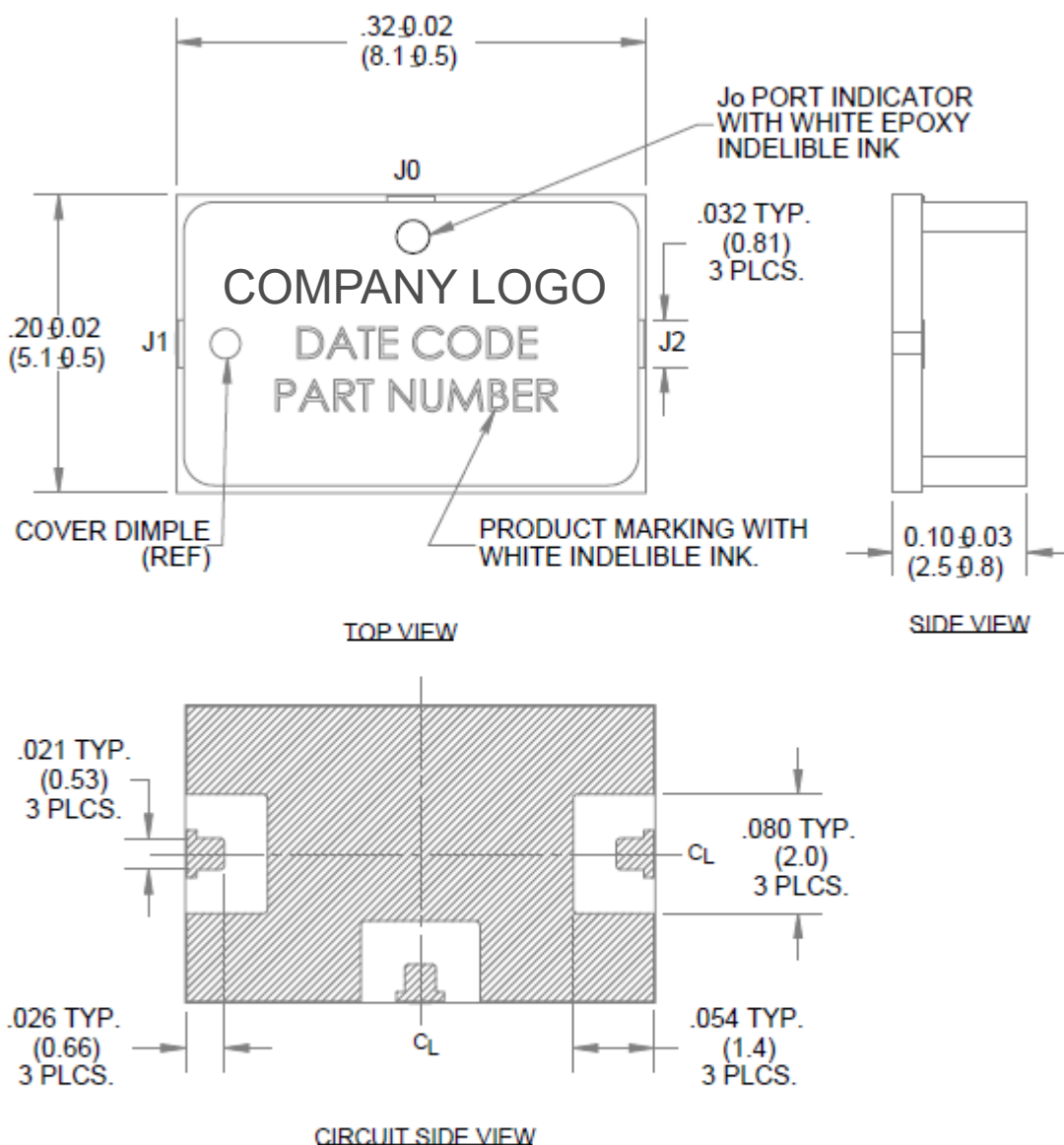
Table 1. Time-Temperature Profile for Sn60/Pb40 or RoHS Type Solders

| Profile Feature | SnPb Solder Assembly | Pb-Free Solder Assembly |
|--|----------------------|-------------------------|
| Average Ramp-Up Rate (T_L to T_p) | 3°C /second maximum | 3°C /second maximum |
| Preheat: | | |
| - Temperature Min (T_{SMIN}) | 100°C | 150°C |
| - Temperature Max (T_{SMAX}) | 150°C | 200°C |
| - Time (min to max)(t_s) | 60-120 s | 60-180 s |
| T_{SMAX} to T_L | | |
| - Ramp-Up Rate | | 3°C/s maximum |
| Time Maintained Above: | | |
| - Temperature (T_L) | 183°C | 217°C |
| - Time (t_L) | 60-150 s | 60-150 s |
| Peak temperature (T_p) | 225 +0/-5°C | 260 +0/-5°C |
| Time Within 5°C of Actual Peak Temperature (t_p) | 10 – 30 s | 20 – 40 s |
| Ramp-Down Rate | 6°C /s maximum | 6°C /s maximum |
| Time 25°C to Peak Temperature | 6 minutes maximum | 8 minutes maximum |

Figure 1. Solder Re-Flow Time-Temperature Profile



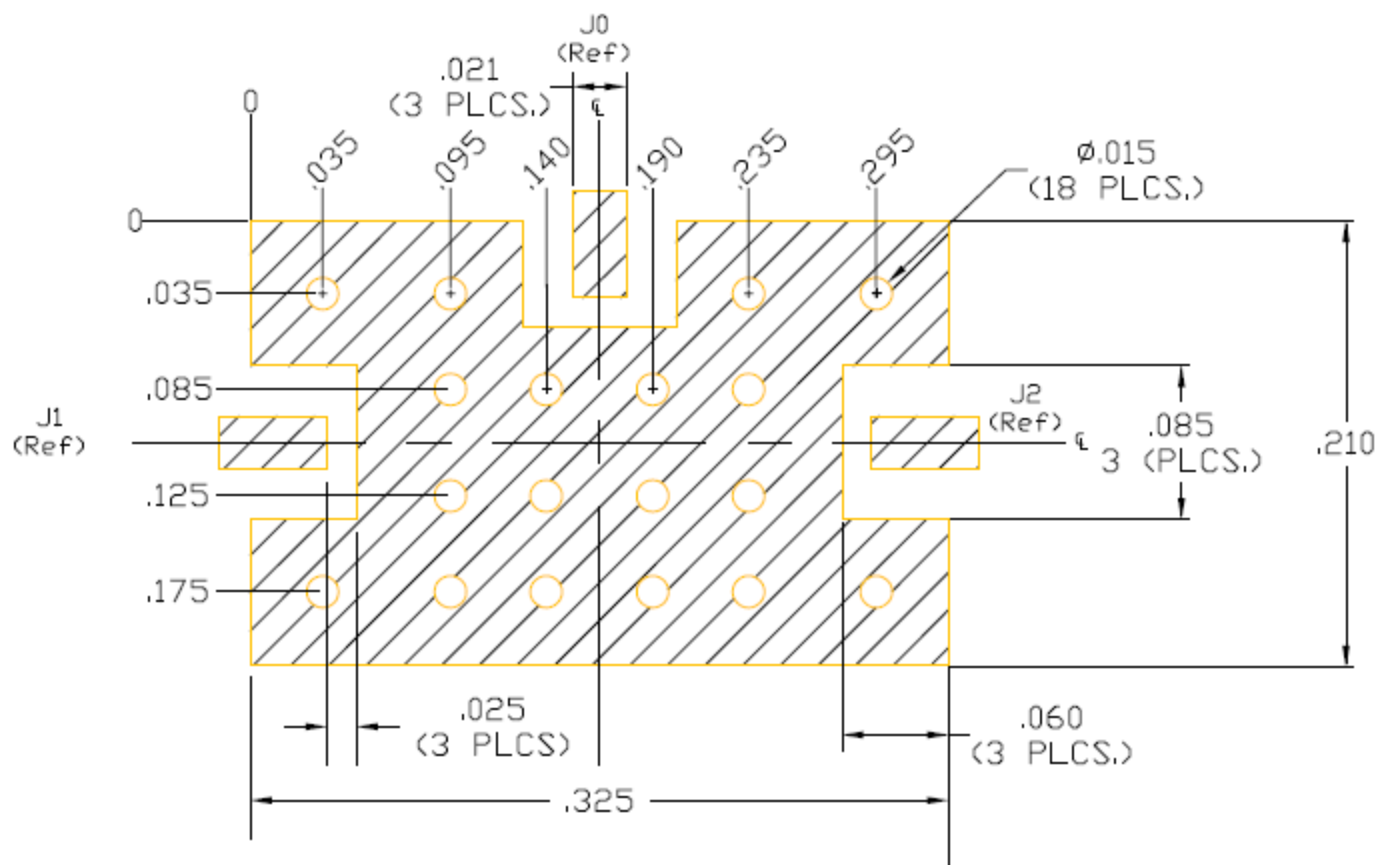
**MSW2060-206, MSW2061-206, and MSW2062-206
SP2T Switch Outline (CS206)**



Notes:

1. Hatched metal area on circuit side of device is RF, DC and thermal ground.

RF Circuit Solder Footprint for Case Style 206 (CS206)



Hatched area is RF, DC, and thermal Ground. Vias should be solid copper fill and gold plated for optimum heat transfer from backside of switch module through Circuit Vias to metal thermal ground.

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